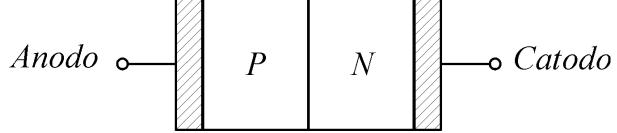
# Elettronica Digitale A.A. 2020-2021

Lezione 08/03/2021



$$p_p = N_A = 10^{17} cm^{-3}$$

$$n_p = \frac{n_i^2}{N} = 10^3 \text{ cm}^{-3}$$

$$n_n = N_D = 10^{16} \text{ cm}^{-3}$$

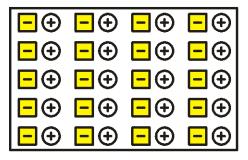
$$n_p = \frac{n_i^2}{N_A} = 10^3 \text{ cm}^{-3}$$
  $p_n = \frac{n_i^2}{N_D} = 10^4 \text{ cm}^{-3}$ 

$$J_p = -qD_p \frac{dp}{dx}$$

$$J_n = qD_n \frac{dn}{dx}$$

$$J_T = J_p + J_n \neq 0 \, !?$$

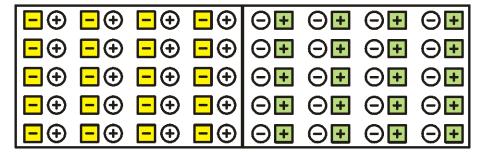
P N



- Accettore ionizzato
- Lacuna

- Donatore ionizzato
- **Θ** Elettrone

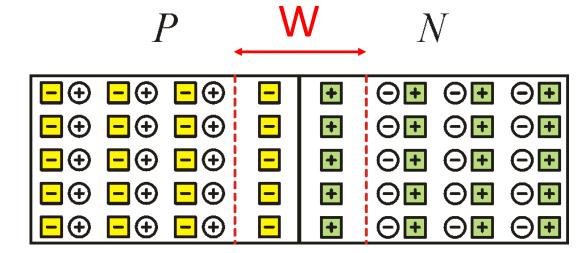


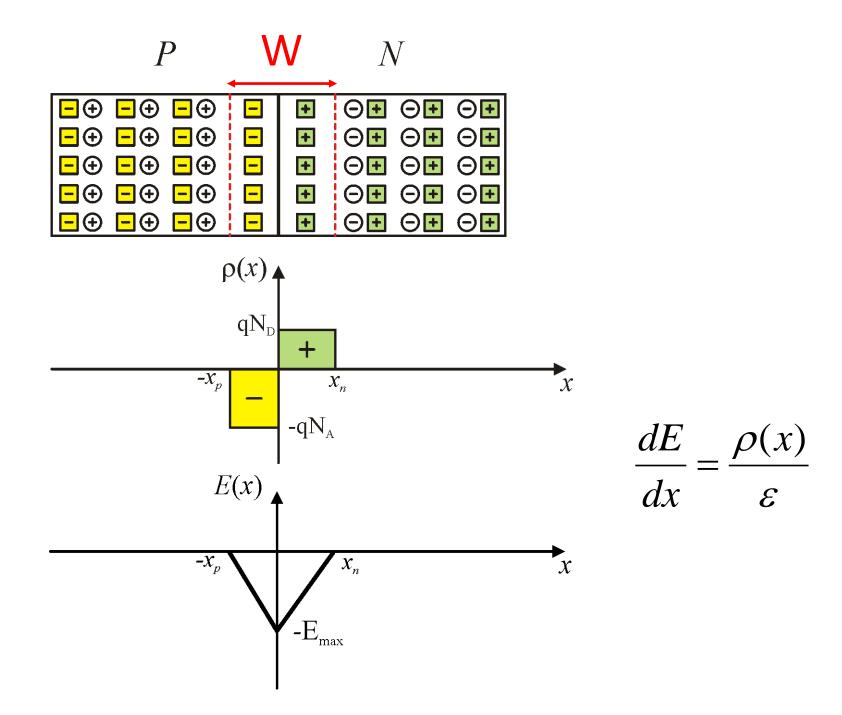


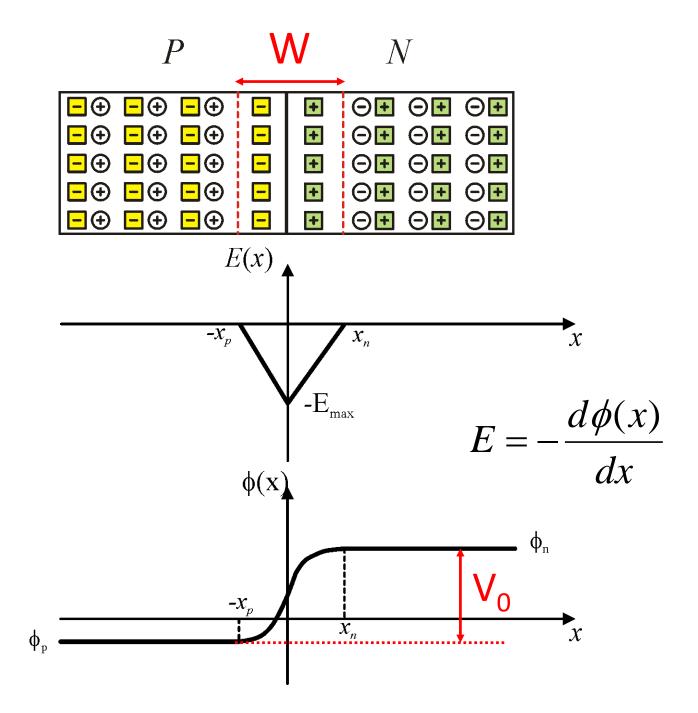


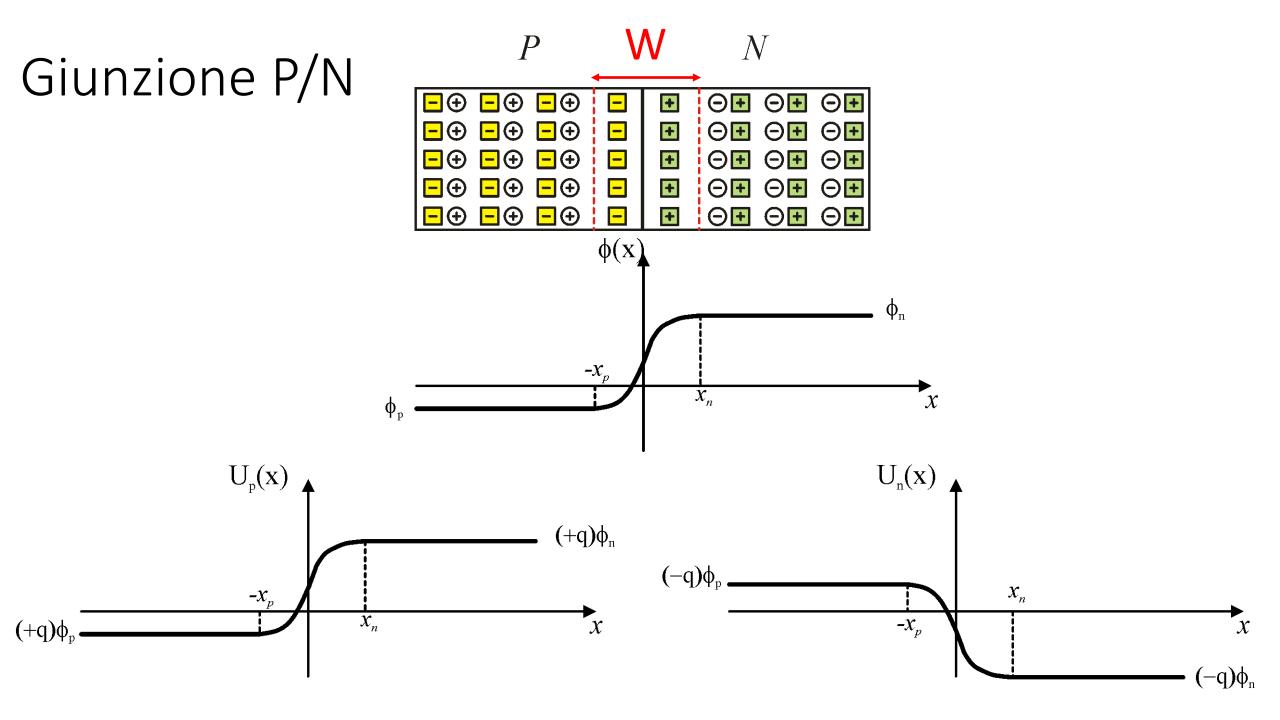
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- Accettore ionizzato
- Lacuna

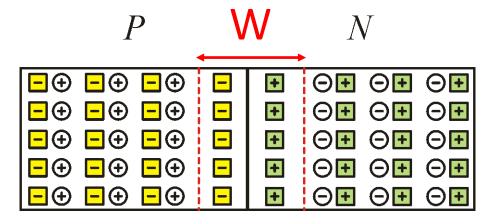
- Donatore ionizzato
- **Θ** Elettrone

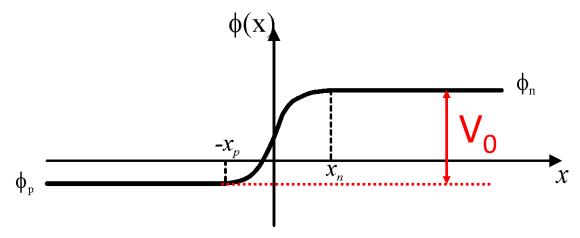




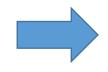




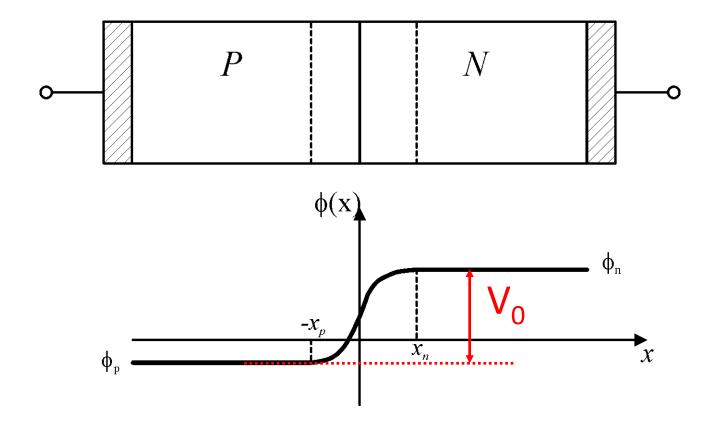




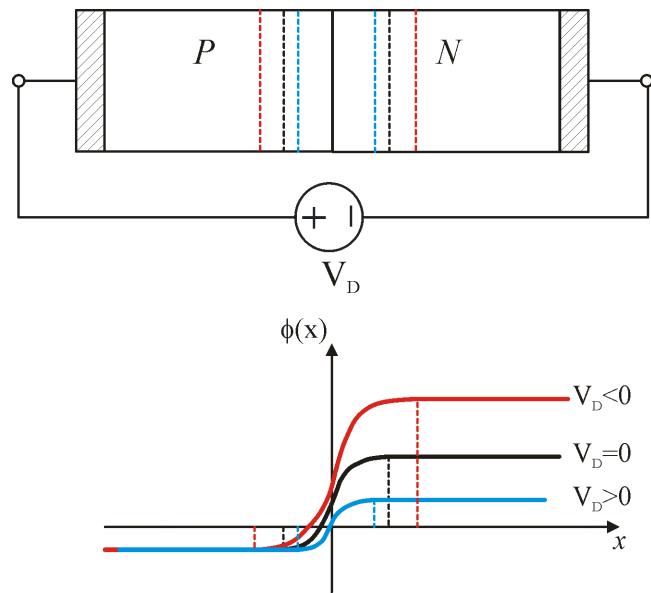
$$egin{aligned} J_n &= J_{n,drift} + J_{n,diffusione} = 0 \ \ J_p &= J_{p,drift} + J_{p,diffusione} = 0 \end{aligned}$$

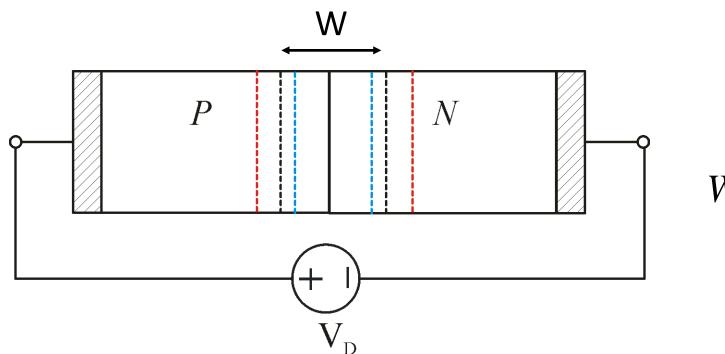


$$V_0 = \frac{kT}{q} \ln \left( \frac{N_A N_D}{n_i^2} \right)$$



La tensione misurata tra i terminali è comunque nulla perché  $V_0$  risulta compensata dai potenziali di contatto metallo-semiconduttore tra le zone p ed n e gli elettrodi esterni.





$$W = \sqrt{\frac{2\varepsilon}{q}} \left( \frac{1}{N_A} + \frac{1}{N_D} \right) (V_0 - V_D)$$

$$I_D = I_S \left( \exp\left(\frac{V_D}{\eta V_T}\right) - 1 \right)$$

Modello di Shockley

$$I_D = I_S \left( \exp\left(\frac{V_D}{\eta V_T}\right) - 1 \right) \qquad \text{Modello di}$$
 Shockley

$$V_T = \frac{kT}{q} \approx 26 \, mV @ 300 \, K$$

 $I_{c}:10^{-18}\div10^{-9}$  A Corrente inversa di saturazione

 $\eta:1\div 2$ Fattore di idealità

$$I_D = I_S \left( \exp\left(\frac{V_D}{\eta V_T}\right) - 1 \right)$$

